NSN 5961-01-195-1318



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-195-1318 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 collector-to-emitter, substaining voltage, base open-circuited and 250.0 collector to base voltage/static/emitter open and 6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 33.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 120.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead

Demilitarization: No

Unit Of Measure:

Shelf Life:

N/a

NSN 5961-01-195-1318 Transistor - Page 2 of 2



Fiig:

A110a0